■ MN103001G

Туре		MN103001G				
Command ROM (x64-bit)		128 K-byte				
Data RAM (×32-bit)		8 K-byte				
Package		LQFP100-P-1414 *Lead-free				
Minimum Instr		17 ns (at 3.0 V to 3.6 V, 60 MHz)				
Interrupts		RESET • IRQ × 8 • NMI • Timer × 18 • SIF × 8 • WDT • A/D • System error				
Timer Counte	er	Cimer counter 0 to 3: 32-bit × 1 (interval timer, event count, timer output, interrupt, clock source for serial I/F, A/D conversion trigger) Clock source				
		Interrupt source				
		Cimer counter 10: 16-bit × 1 (interval timer, event count, PWM output, toggle output (2 lines), interrupt, input capture (2 lines), one-shot output) Clock source ————————————————————————————————————				
		Interrupt source				
Serial Interfac	е	Serial 0.77, 8-bit X (clock synchronous, start-stop synchronous, I ² C mode)				
		Serial 1, 2: 7-, 8-bit × 2 (clock synchronous mode) Serial 3: 7-, 8-bit × 1 (start-stop synchronous mode) Clock source(clock synchronous mode, start-stop synchronous mode) IOCLK; underflow of timer counter; external clock (I*C mode) IOCLK; underflow of timer counter				
I/O Pins	I/O	• Common use				
	Output	5 • Common use				
	Input	4 • Common use				

A/D Inputs	10-bit × 4-ch.
PWM	16-bit × 1-ch., 8-bit × 8-ch. (common with timer)
ICR	16-bit × 2-ch. (common with OCR)
OCR	16-bit × 2-ch., 8-bit × 8-ch. (common partially with ICR)

Electrical Characteristics

Supply current

Parameter	Symbol	Condition		Limit		
r al allietei	Symbol			typ	max	Unit
Operating supply current	IDD1	VDD, PVDD, AVDD = 3.3 V VI = VDD or VSS fosc = 15.0 MHz CKSEL pin = Hi level At internal = 60 MHz Output open	S.Mai	or of the	180	mA
Supply current at stopping	IDD4	VDD , PVDD , AVDD = 3.6 V VI = VDD or VSS fosc = Oscillation stopped Output open	et.		100	μА

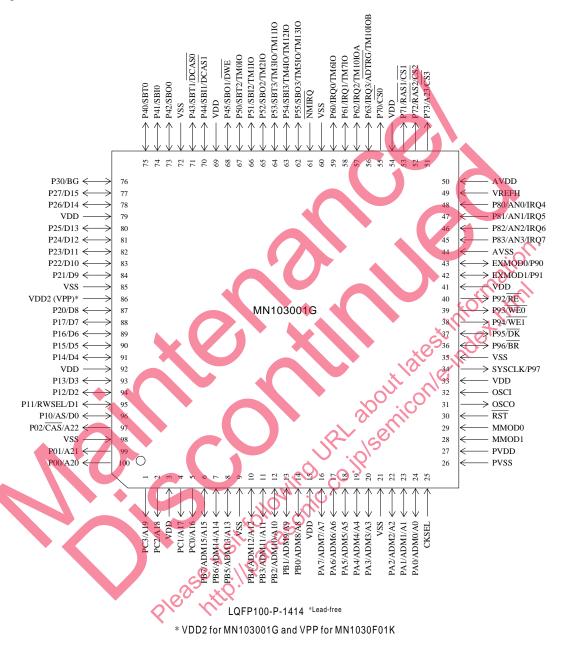
$(Ta = -20^{\circ}C \text{ to } +70^{\circ}C)$

A/D conversion performance

Parameter	Symbol	Condition	Limit			Unit
r di dillicte	Symbol		min	typ	max	Oiiit
Resolution		Chli ic.			10	Bits
A/D conversion absolute error		VREF+ = 3.3 V			± 7	LSB
A/D conversion relative error		A/D conversion clock = 5 MHz			± 5	LSB
A/D conversion time		AD Conversion Clock – 3 WHZ	2.8			μs

 $(Ta = -20^{\circ}C \text{ to } +70^{\circ}C, \text{ AVDD} = 3.3 \text{ V}, \text{ AVSS} = 0 \text{ V})$

Pin Assignment



Support Tool

In-circuit Emulator	PX-ICE103001-LQFP100-P-1414				
On-board Development Tools	PX-ODB103S-O				
·	CSIDE-MN10300 (Computex Co., Ltd, product)				
Flash Memory Built-in Type	Туре	MN1030F01K			
	Command ROM (× 64-bit)	256 K-byte			
	Data RAM (× 32-bit)	8 K-byte			
	Minimum instruction execution time	25 ns (at 3.0 V to 3.6 V, 40 MHz)			
	Package	LQFP100-P-1414 *Lead-free			



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